

Triac Medium Power Use

> REJ03G0306-0200 Rev.2.00 Nov.09.2004

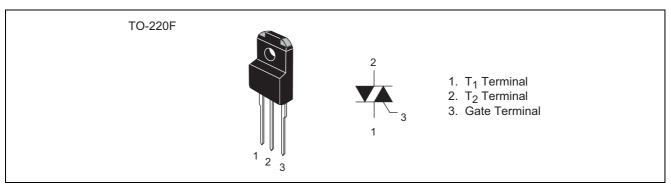
Features

- I_{T (RMS)} : 16 A
- V_{DRM} : 600 V
- I_{FGTI} , I_{RGTI} , I_{RGT} : 30 mA (20 mA)^{Note5}
- Viso : 1500 V

Outline

- Insulated Type Planar Passivation Type
- UL Recognized : Yellow Card No. E223904

File No. E80271



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Applications

Contactless AC switch, light dimmer, electronic flasher unit, hair drier, control of household equipment such as TV sets, refrigerator, washing machine, electric fan, and other general controlling devices

Maximum Ratings

Parameter	Symbol	Voltage class	Unit	
Falanielei	Symbol	12		
Repetitive peak off-state voltage ^{Note1}	V _{DRM}	600	V	
Non-repetitive peak off-state voltage ^{Note1}	V _{DSM}	720	V	

BCR16PM-12L

Parameter	Symbol	Ratings	Unit	Conditions	
RMS on-state current	I _{T (RMS)}	16	A	Commercial frequency, sine full wave 360° conduction, Tc = 71°C	
Surge on-state current	I _{TSM}	160	A	60Hz sinewave 1 full cycle, peak value, non-repetitive	
I ² t for fusing	l ² t	106.5	A ² s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current	
Peak gate power dissipation	P _{GM}	5.0	W		
Average gate power dissipation	P _{G (AV)}	0.5	W		
Peak gate voltage	V _{GM}	10	V		
Peak gate current	I _{GM}	2	A		
Junction temperature	Tj	- 40 to +125	°C		
Storage temperature	Tstg	- 40 to +125	°C		
Mass	_	2.0	g	Typical value	
Isolation voltage	Viso	1500	V	Ta = 25°C, AC 1 minute, T ₁ ·T ₂ ·G terminal to case	

Notes: 1. Gate open.

Electrical Characteristics

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cur	rrent	I _{DRM}	_	—	2.0	mA	Tj = 125°C, V _{DRM} applied
On-state voltage		V _{TM}	_	—	1.5	V	$Tc = 25^{\circ}C$, $I_{TM} = 25 A$, Instantaneous measurement
Gate trigger voltage ^{Note2}	Ι	V _{FGTI}	_	—	1.5	V	$Tj=25^{\circ}C,\ V_{D}=6\ V,\ R_{L}=6\ \Omega,$
	II	V _{RGTI}		—	1.5	V	$R_G = 330 \Omega$
	III	V _{RGTIII}		—	1.5	V	
Gate trigger current ^{Note2}	Ι	I _{FGTI}		—	30 ^{Note5}	mA	$Tj=25^{\circ}C,\ V_{D}=6\ V,\ R_{L}=6\ \Omega,$
	II	I _{RGTI}		_	30 ^{Note5}	mA	$R_G = 330 \Omega$
	III	I _{RGTIII}		_	30 ^{Note5}	mA	
Gate non-trigger voltage		V_{GD}	0.2	—	—	V	$Tj = 125^{\circ}C, V_D = 1/2 V_{DRM}$
Thermal resistance		R _{th (j-c)}	_	—	3.0	°C/W	Junction to case ^{Note3}
Critical-rate of rise of off-sta commutating voltage ^{Note4}	te	(dv/dt)c	10	—	—	V/µs	Tj = 125°C

Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

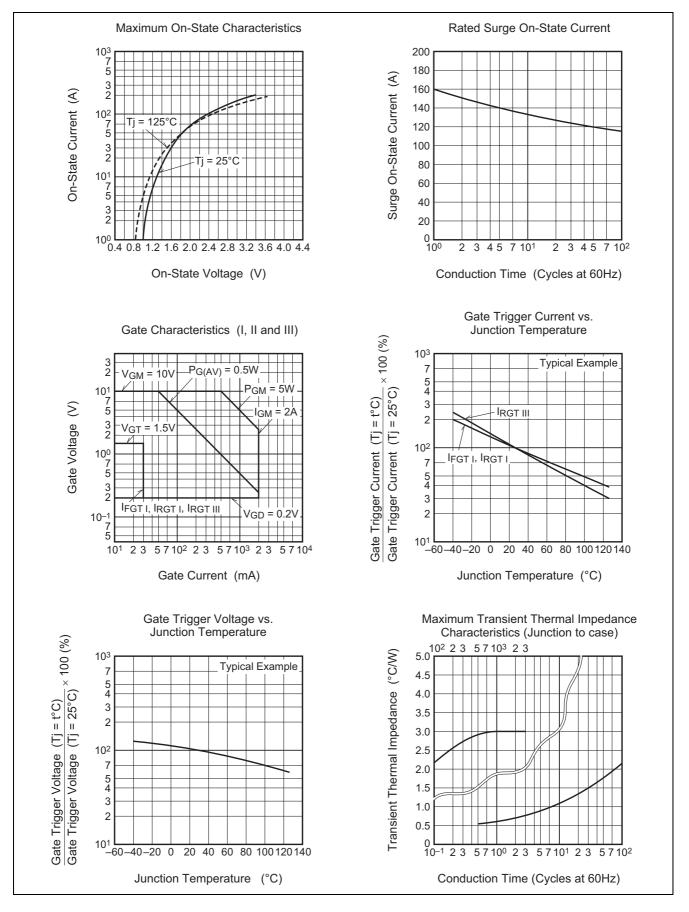
3. The contact thermal resistance $R_{th\,(c\text{-}f)}$ in case of greasing is 0.5°C/W.

4. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

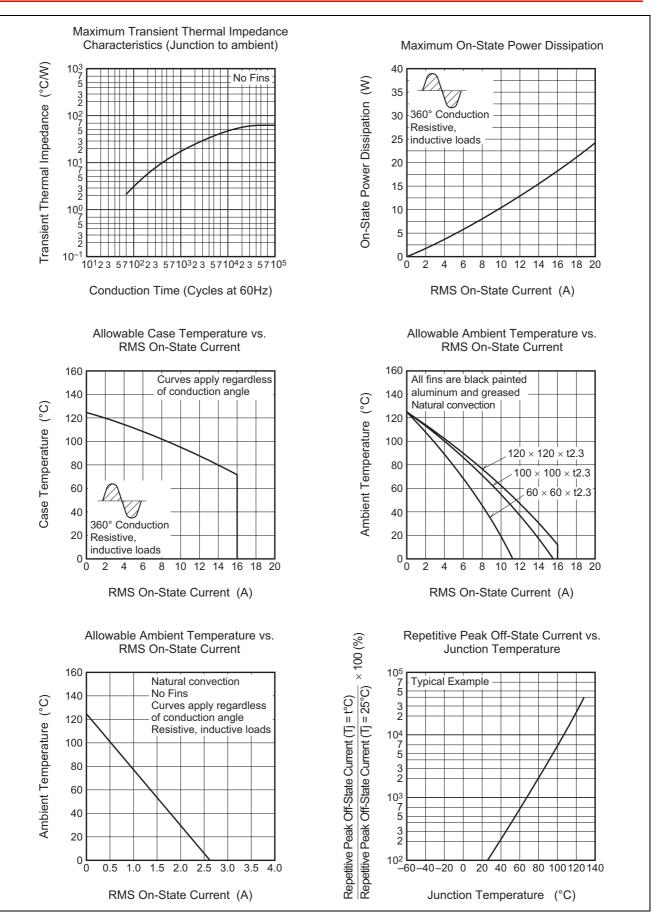
5. High sensitivity (I_{GT} \leq 20mA) is also available. (I_{GT} item: 1)

Test conditions	Commutating voltage and current waveforms (inductive load)			
1. Junction temperature Tj = 125°C	Supply Voltage			
 Rate of decay of on-state commutating current (di/dt)c = - 8.0 A/ms 	Main Current → Time			
3. Peak off-state voltage V _D = 400 V	Main Voltage Time (dv/dt)cVD			

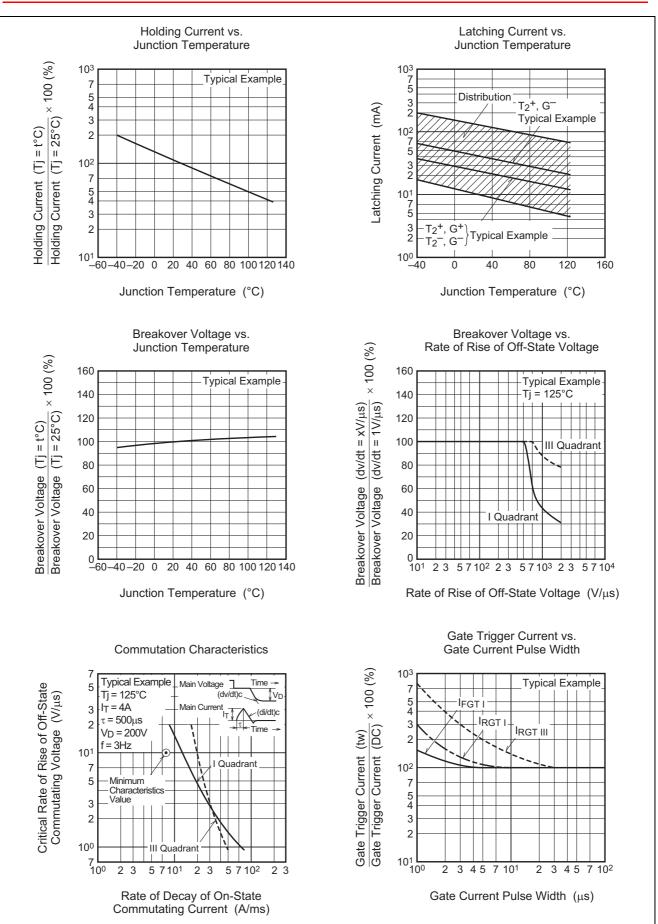
Performance Curves



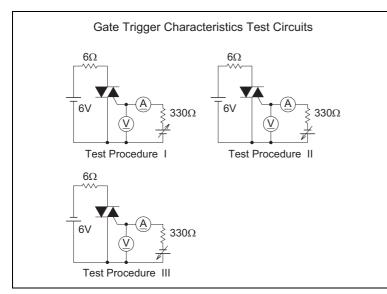




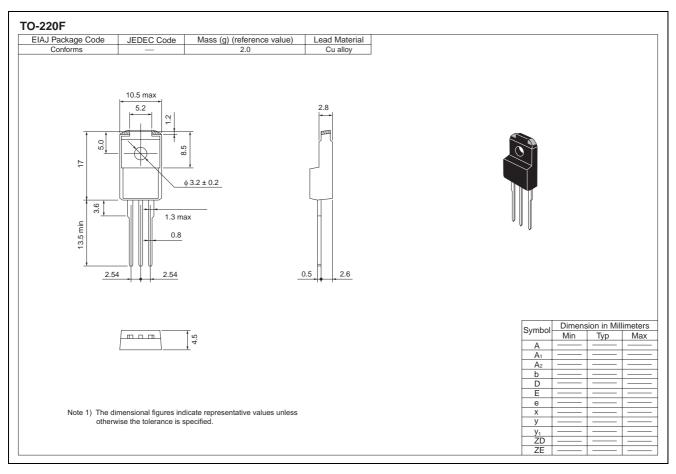








Package Dimensions



Order Code

Standard packing	Quantity	Standard order code	Standard order code example
Vinyl sack	100	Type name +A	BCR16PM-12LA
Plastic Magazine (Tube)	50	Type name +A – Lead forming code	BCR16PM-12LA-A8
	Vinyl sack	Vinyl sack 100	Vinyl sack 100 Type name +A

Note : Please confirm the specification about the shipping in detail.

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